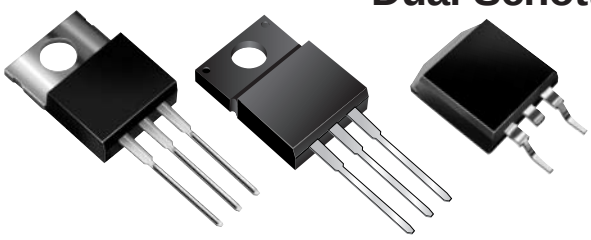
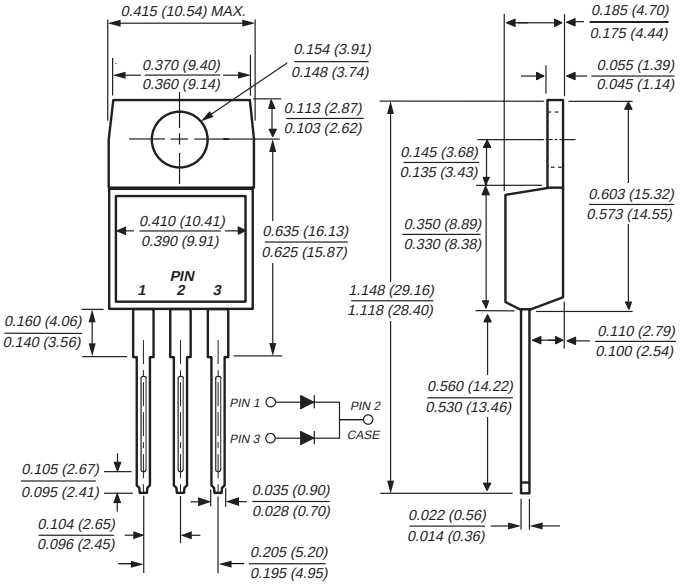
Vishay Semiconductors
formerly General Semiconductor

Dual Schottky Barrier Rectifier

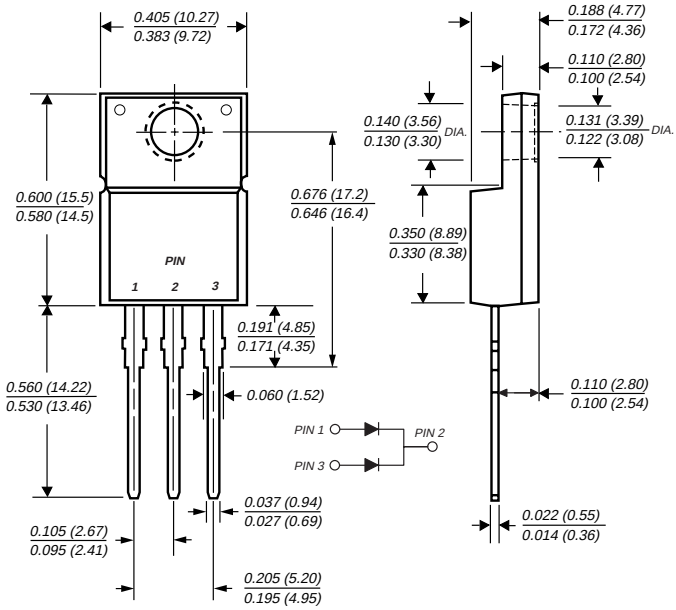
Reverse Voltage 35 to 60V
Forward Current 15A



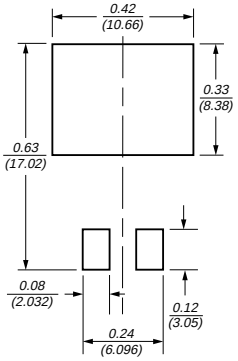
TO-220AB (MBR15xxCT)



ITO-220AB (MBRF15xxCT)

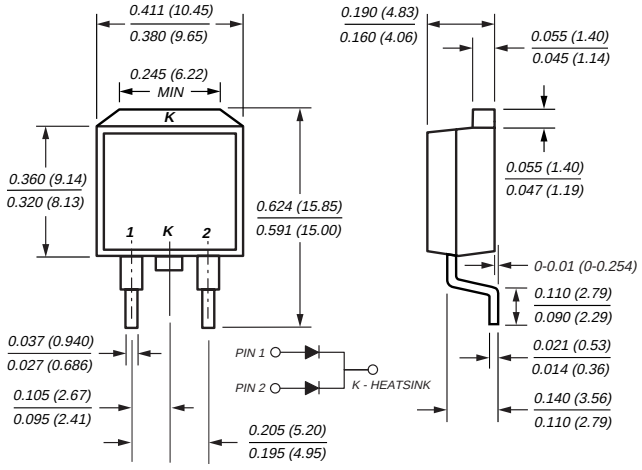


Mounting Pad Layout TO-263AB



Dimensions in inches and (millimeters)

TO-263AB (MBRB15xxCT)



Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Dual rectifier construction, positive center tap
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Guardring for overvoltage protection
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

Case: JEDEC TO-220AB, ITO-220AB & TO-263AB molded plastic body

Terminals: Plated leads, solderable per MIL-STD-750, Method 2026

Polarity: As marked

Mounting Position: Any

Mounting Torque: 10 in-lbs maximum

Weight: 0.08 ounce, 2.24 grams

Maximum Ratings (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	V
Working peak reverse voltage	V_{RWM}	35	45	50	60	V
Maximum DC blocking voltage	V_{DC}	35	45	50	60	V
Maximum average forward rectified current *Total device* / at TC = 105°C *Per leg*	$I_{F(AV)}$	15 / 7.5				A
Peak repetitive forward current at T_C = 105°C (rated V_R, 20 KHz sq. wave)	I_{FRM}	15				A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150				A
Peak repetitive reverse surge current per leg at t_p = 2.0µs, 1KHz	I_{RRM}	1.0		0.5		A
Voltage rate of change (rated V_R)	dv/dt	10,000				V/µs
Operating junction temperature range	T_J	–65 to +150				°C
Storage temperature range	T_{STG}	–65 to +175				°C
RMS Isolation voltage (MBRF type only) from terminals to heatsink with t = 1.0 second, RH ≤ 30%	V_{ISOL}	4500 (NOTE 1) 3500 (NOTE 2) 1500 (NOTE 3)				V

Electrical Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	Unit
Maximum instantaneous forward voltage per leg (Note 4) at I_F = 7.5A, T_C = 25°C at I_F = 7.5A, T_C = 125°C at I_F = 15A, T_C = 25°C at I_F = 15A, T_C =1 25°C	V_F		– 0.57 0.84 0.72		0.75 0.65 – –	V
Maximum instantaneous reverse current at rated DC blocking voltage per leg (Note 4) T_C = 25°C / T_C =125°C	I_R		0.1 15		1.0 50	mA

Thermal Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR	MBRF	MBRB	Unit
Maximum thermal resistance per leg	$R_{\Theta JA}$ $R_{\Theta JC}$	60 3.0	– 5.0	60 3.0	°C/W

Notes:
(1) Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset
(2) Clip mounting (on case), where leads do overlap heatsink
(3) Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19")
(4) Pulse test: 300µs pulse width, 1% duty cycle

Ordering Information

Product	Case	Package Code	Package Option
MBR1535CT - MBR1560CT	TO-220AB	45	Anti-Static tube, 50/tube, 2K/carton
MBRF1535CT - MBRF1560CT	ITO-220AB	45	Anti-Static tube, 50/tube, 2K/carton
MBRB1535CT - MBRB1560CT	TO-263AB	31 45 81	13" reel, 800/reel, 4.8K/carton Anti-Static tube, 50/tube, 2K/carton Anti-Static 13" reel, 800/reel, 4.8K/carton

Ratings and Characteristic Curves (T_A = 25°C unless otherwise noted)

Fig. 1 – Forward Current Derating Curve

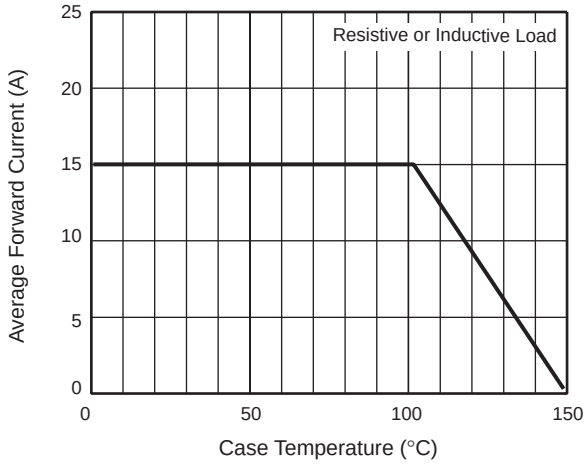


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current Per Leg

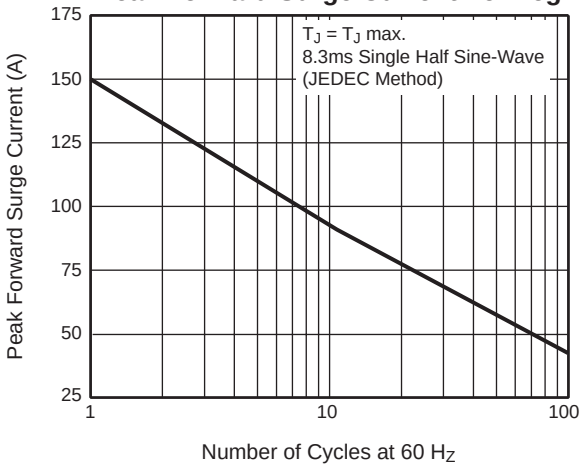


Fig. 3 – Typical Instantaneous Forward Characteristics Per Leg

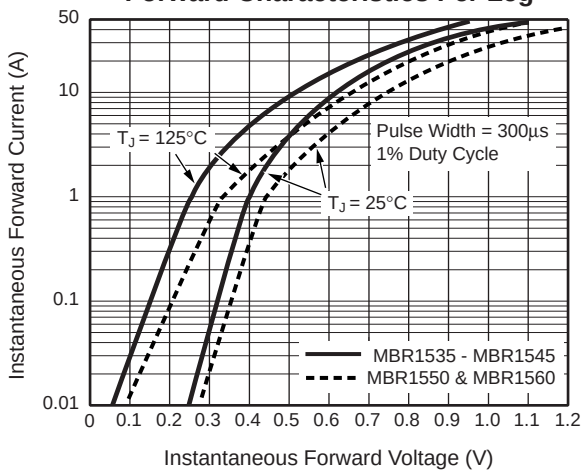


Fig. 4 – Typical Reverse Characteristics Per Leg

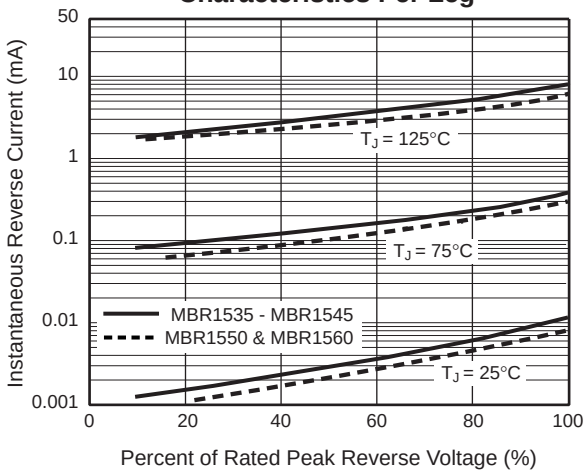


Fig. 5 – Typical Junction Capacitance Per Leg

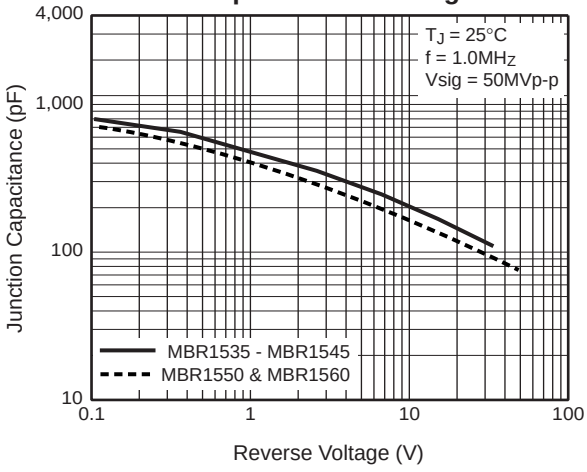


Fig. 6 – Typical Transient Thermal Impedance Per Leg

